5.0mm x 6.0mm SURFACE MOUNT LED LAMP

PRELIMINARY SPEC

ATTENTION OBSERVE PRECAUTIONS FOR HANDLING ELECTROSTATIC DISCHARGE SENSITIVE DEVICES

Features

- Chips can be controlled separately.
- Suitable for all SMT assembly and solder process.
- Available on tape and reel.
- Package: 500pcs / reel.

Package Dimensions

- Moisture sensitivity level : level 4.
- · RoHS compliant.

Part Number: AAAF5060QBDZGSEEC

Blue Green Hyper Red

Description

The Blue source color devices are made with AlGaInN on Sapphire Light Emitting Diode.

The Green source color devices are made with InGaN on Sapphire Light Emitting Diode.

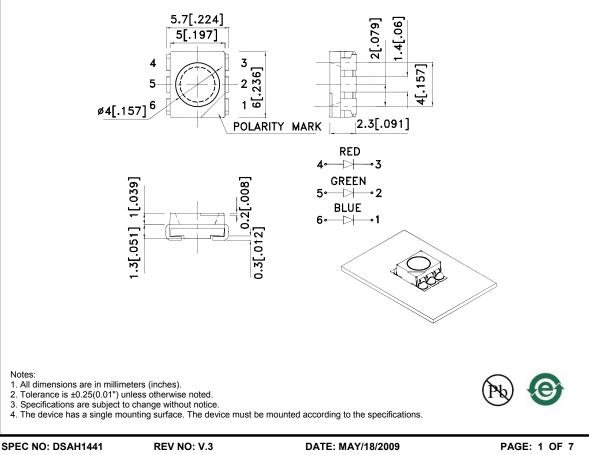
The Hyper Red source color devices are made with Al-

GaInP on GaAs substrate Light Emitting Diode.

Static electricity and surge damage the LEDS.

It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs.

All devices, equipment and machinery must be electrically grounded.



DRAWN: Ting.Li

ERP: 1201002599

CHECKED: Allen Liu

APPROVED: WYNEC

Selection Guide								
Part No.	Dice	Lens Type	lv (mcd) [2] @ 30mA *50mA		Viewing Angle [1]			
			Min.	Тур.	201/2			
AAAF5060QBDZGSEEC	Blue (AlGaInN)		110	250	100°			
	Green (InGaN)	WATER CLEAR	280	650				
	Hyper Red (AlGaInP)]	*650	*1000				

Notes:

01/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
*Luminous intensity with asterisk is measured at 50mA; Luminous intensity/ luminous Flux: +/-15%.

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions		
λpeak	Peak Wavelength	Blue Green Hyper Red	468 515 630		nm	l⊧=20mA		
λD [1]	Dominant Wavelength	Blue Green Hyper Red	470 525 621		nm	l⊧=20mA		
Δλ1/2	Spectral Line Half-width	Blue Green Hyper Red	25 30 20		nm	l⊧=20mA		
С	Capacitance	Blue Green Hyper Red	100 45 25		pF	VF=0V;f=1MHz		
Vf [2]	Forward Voltage	Blue Green Hyper Red	3.3 3.3 2	4 4.1 2.5	V	l⊧=20mA		
lr	Reverse Current	Blue Green Hyper Red		10 10 10	uA	VR=5V		

Electrical / Optical Characteristics at TA=25°C

Notes:

1.Wavelength: +/-1nm. 2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

Parameter	Blue	Green	Hyper Red	Units		
Power dissipation[2]		mW				
DC Forward Current	30	30	50	mA		
Peak Forward Current [1]	150	150	195	mA		
Reverse Voltage		V				
Operating Temperature	-40°C To +85°C					
Storage Temperature	-40°C To +85°C					

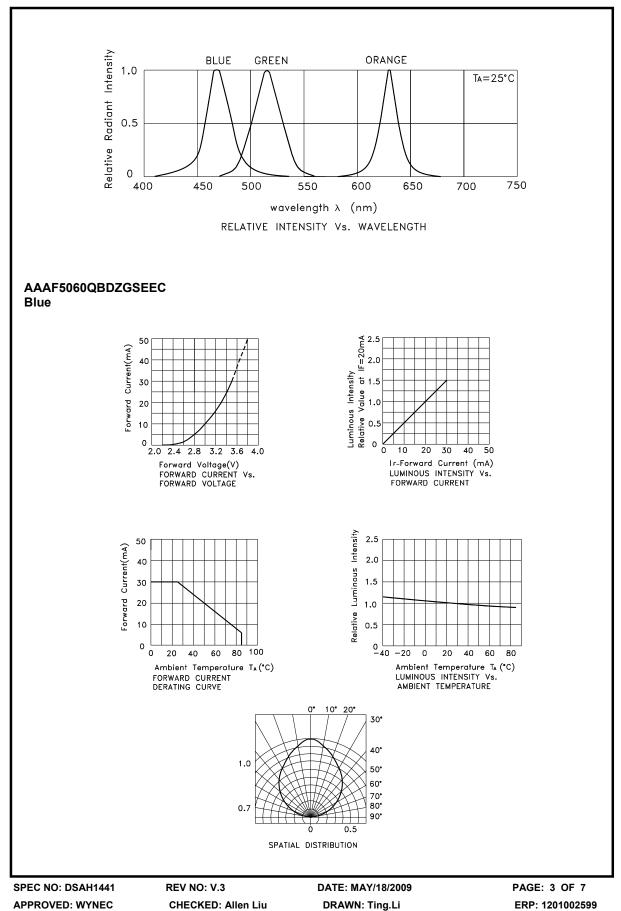
Notes:

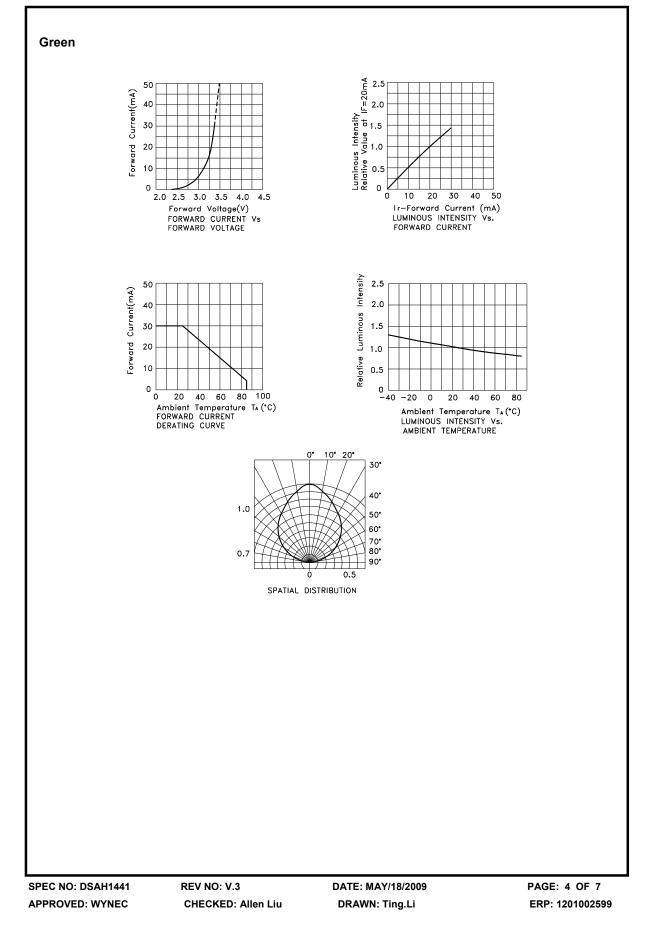
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. Within 350mW at all chips are lightened.

SPEC NO: DSAH1441 APPROVED: WYNEC

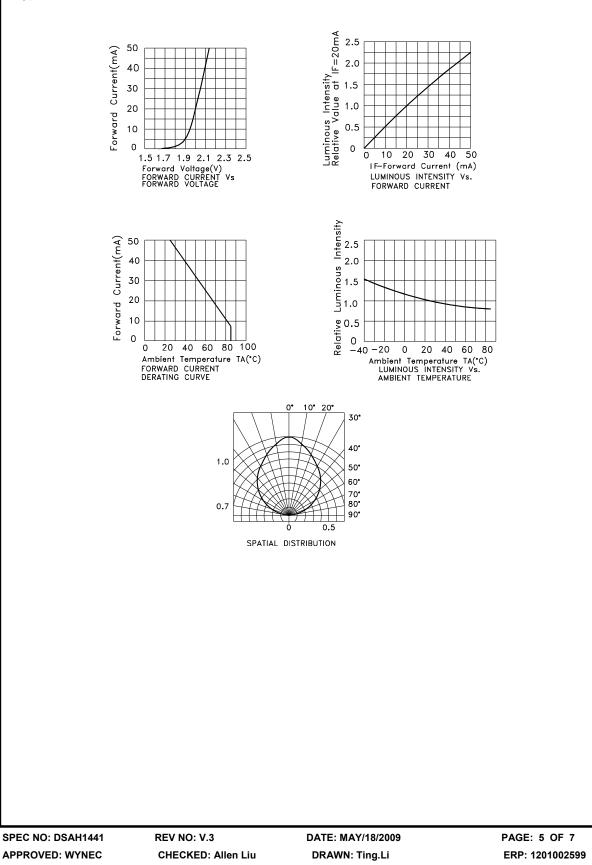
REV NO: V.3 CHECKED: Allen Liu DATE: MAY/18/2009 DRAWN: Ting.Li

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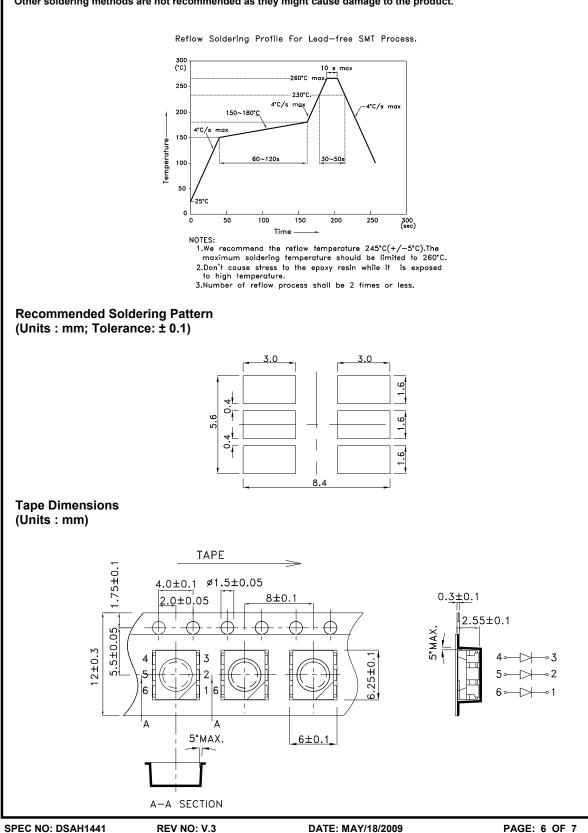






AAAF5060QBDZGSEEC

Reflow soldering is recommended and the soldering profile is shown below. Other soldering methods are not recommended as they might cause damage to the product.



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